

KSC3488

Low Frequency Power Amplifier

- Complement to KSA1378
- Collector Dissipation : P_C=300mW



1.Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	30	V
V _{CEO}	Collector-Emitter Voltage	25	V
V _{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	300	mA
P _C	Collector Power Dissipation	300	mW
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	-55 ~ 150	°C

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C=100\mu A, I_E=0$	30			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =10mA, I _B =0	25			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E=10\mu A, I_C=0$	5			V
I _{CBO}	Collector Cut-off Current	V _{CB} =25V, I _E =0			0.1	μΑ
I _{EBO}	Emitter Cut-off Current	V_{EB} =3V, I_{C} =0			0.1	μΑ
h _{FE}	DC Current Gain	V _{CE} =1V, I _C =50mA	70		400	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =300mA, I _B =30mA		0.14	0.4	V

h_{FE} Classification

Classification	0	Υ	G
h _{FE}	70 ~ 140	120 ~ 240	200 ~ 400

Typical Characteristics

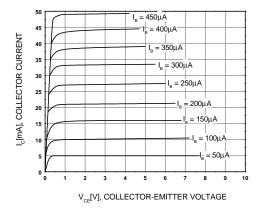


Figure 1. Static Characteristic

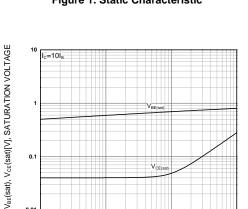


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

I_c[mA], COLLECTOR CURRENT

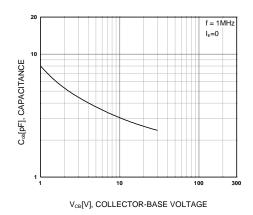


Figure 5. Collector Output Capacitance

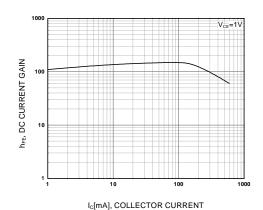


Figure 2. DC current Gain

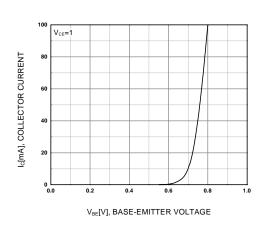


Figure 4. Base-Emitter On Voltage

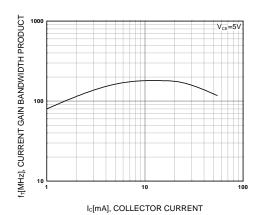
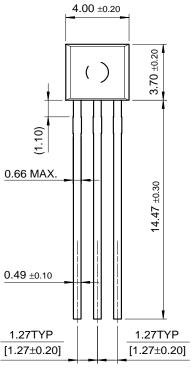


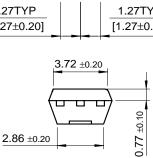
Figure 6. Current Gain Bandwidth Product

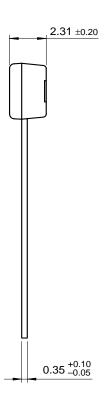
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Package Dimensions

TO-92S







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
CROSSVOLT™	FRFET™	MicroPak™	QFET™	SuperSOT™-8
DOME™	GlobalOptoisolator™	MICROWIRE™	QS™	SyncFET™
EcoSPARK™	GTO™	MSX™	QT Optoelectronics™	TinyLogic™
E ² CMOS™	HiSeC™	MSXPro™	Quiet Series™	TruTranslation™
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Across the board.	. Around the world.™	OCXPro™	RapidConnect™	UltraFET [®]
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Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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